2SJ0536G

Silicon P-channel MOSFET

Secondary battery packs (Li ion battery, etc.) For switching circuits

■ Features

- High-speed switching
- S-mini type package, allowing downsizing of the sets and automatic insertion through the tape/magazine packing
- Low voltage drive (V_{th}: -1.0 V to 2.0 V)
- Low ON resistance

■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Drain-sourse surrender voltage	V _{DSS}	-30	V	
Gate-source voltage (Drain open)	V _{GSO}	±20	V	
Drain current	I_{D}	-100	mA	
Peak drain current	I_{DP}	-200	mA	
Power dissipation	P_{D}	150	mW	
Channel temperature	T _{ch}	150	°C	
Storage temperature	T_{stg}	-55 to +150	°C	

Package

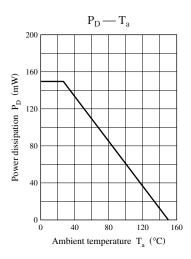
- Code SMini3-F2
- Marking Symbol: 2C
- Pin Name
 - 1: Gate
- 2: Source
- 3: Drain

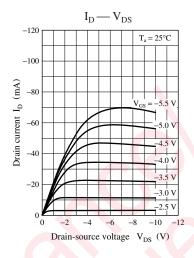
■ Electrical Characteristics $T_a = 25$ °C ± 3 °C

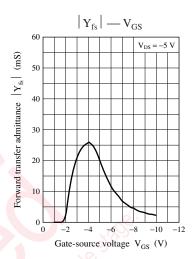
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Drain-source cutoff current	I_{DSS}	$V_{DS} = -30 \text{ V}, V_{GS} = 0$	100	0,	- 0.1	μΑ
Gate-source cutoff current	I_{GSS}	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0$		<i>)</i> -	±1.0	μΑ
Gate threshold voltage	V_{th}	$V_{DS} = -5 \text{ V}, I_D = -1 \mu A$	-1.0		-2.0	V
Forward transfer admittance	Y _{fs}	$V_{DS} = -5 \text{ V}, I_D = -10 \text{ mA}$	8			mS
Drain-source ON resistance	R _{DS(on)}	$V_{GS} = -5 \text{ V}, I_D = -10 \text{ mA}$		50	75	Ω
Turn-on time	t _{on}	$V_{DD} = -5 \text{ V}, V_{GS} = 0 \text{ V} \sim -5 \text{ V}$		100		μs
in the second second		$R_L = 200 \Omega$				
Turn-off time	t _{off}	$V_{DD} = -5 \text{ V}, V_{GS} = -5 \text{ V} \sim 0 \text{ V}$		25		μs
		$R_L = 200 \Omega$				

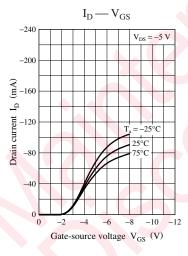
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

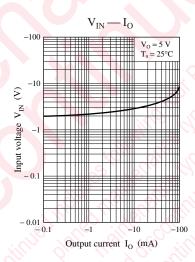
^{2.} Observe precautions for handling. Electrostatic sensitive devices.



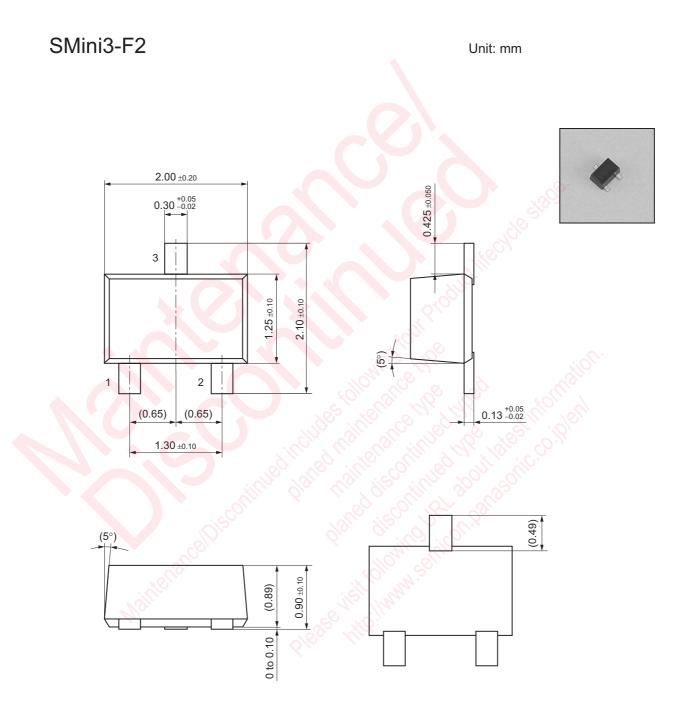








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